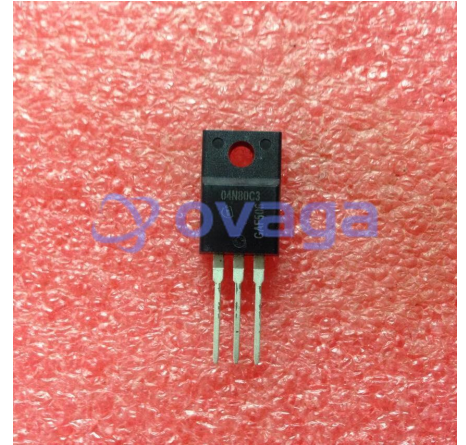


N-Channel MOSFETs (>500V...900V); Package: PG-TO220-3; VDS (max): 800.0 V; Package: TO-220 FullPAK; RDS(ON) @ TJ=25°C VGS=10: 1,300.0 mOhm; ID(max) @ TC=25°C: 4.0 A; IDpuls (max): 12.0 A; MOSFET COOL MOS PWR TRANS 800V 4A

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-220FP
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for SPA04N80C3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

SPA04N80C3 is a power MOSFET transistor.

Features

It has a voltage rating of 800V and can handle a continuous current of 4A.

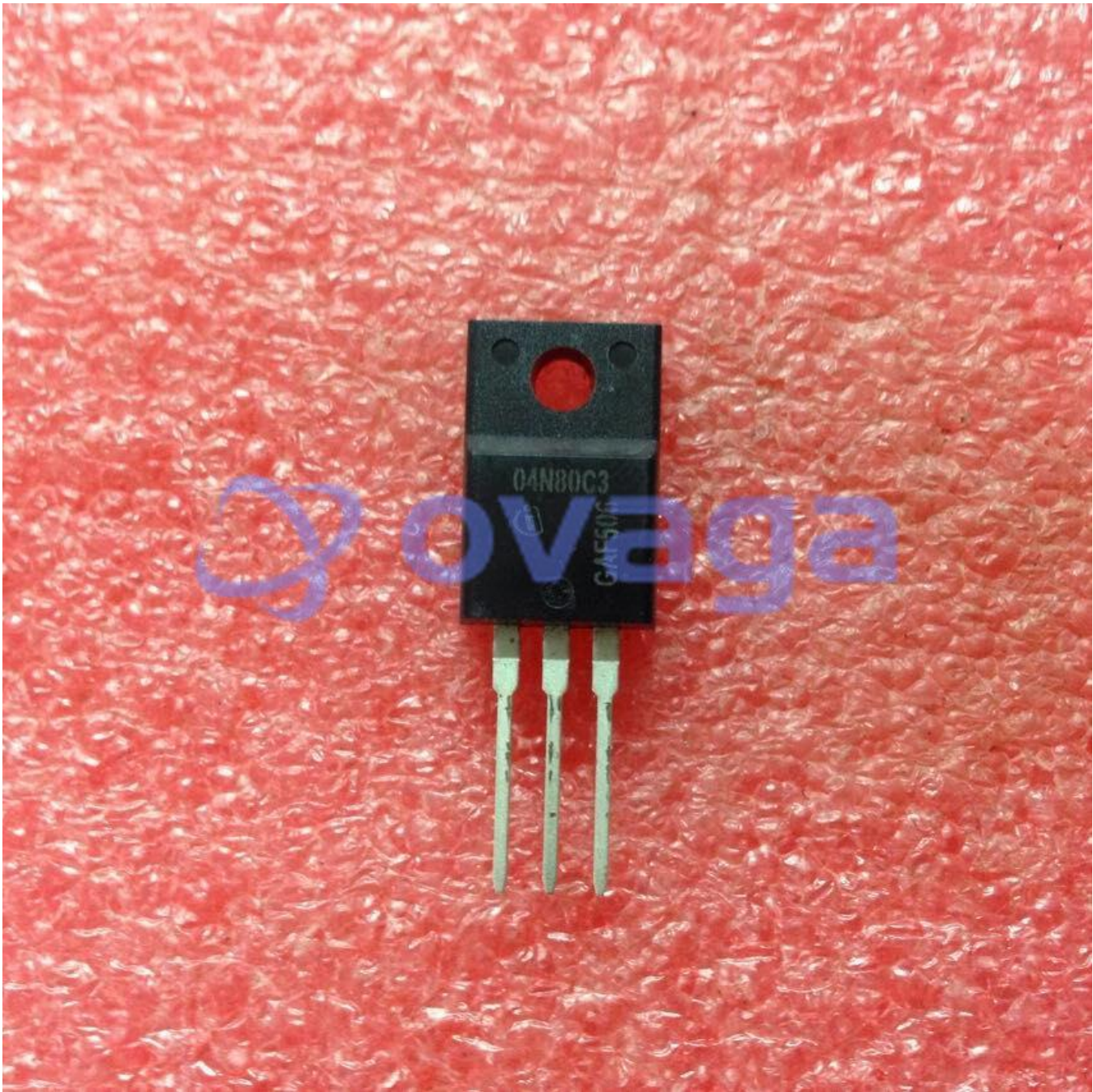
The device has a low on-state resistance (RDS(on)) of 1.1 ohms.

It is designed with advanced MOSFET technology, which ensures high switching speed and efficiency.

Application

The SPA04N80C3 is commonly used in switching power supplies, lighting systems, and motor control circuits.

It is also used in electronic ballasts for fluorescent lamps and other high-frequency applications.



Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

Infineon Technologies Corporation
TO-220AB



[SPP07N60S5](#)

Infineon Technologies Corporation
P-TO220-3-1



[SPP11N60C3XKSA1](#)

Infineon Technologies Corporation
PG-TO220



[IRF640NSPBF](#)

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PAK-3



[SPD03N60S5](#)

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TO-252



[SPP20N60CFD](#)

Infineon Technologies Corporation
TO-220AB